



# 2SK3557

## N-Channel JFET 15V, 10 to 32mA, 35mS, CP

ON Semiconductor®

<http://onsemi.com>

### Applications

- AM tuner RF amplification
- Low noise amplifier

### Features

- Large  $|y_{fs}|$
- Small  $C_{iss}$
- Ultrasmall-sized package permitting 2SK3557-applied sets to be made smaller and slimer
- Ultralow noise figure

### Specifications

Absolute Maximum Ratings at  $T_a=25^\circ\text{C}$ 

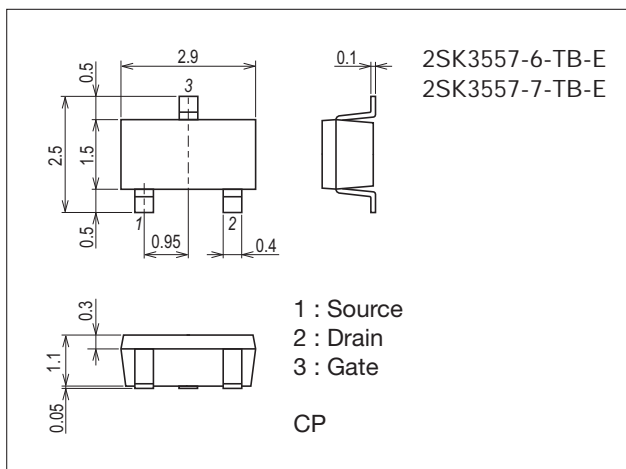
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSX}$		15	V
Gate-to-Drain Voltage	$V_{GDS}$		-15	V
Gate Current	$I_G$		10	mA
Drain Current	$I_D$		50	mA
Allowable Power Dissipation	$P_D$		200	mW
Junction Temperature	$T_j$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

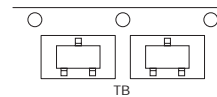
7013A-011



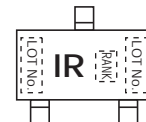
### Product & Package Information

- Package : CP
- JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB
- Minimum Packing Quantity : 3,000 pcs./reel

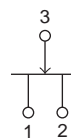
### Packing Type: TL



### Marking



### Electrical Connection



# 2SK3557

## Electrical Characteristics at Ta=25°C

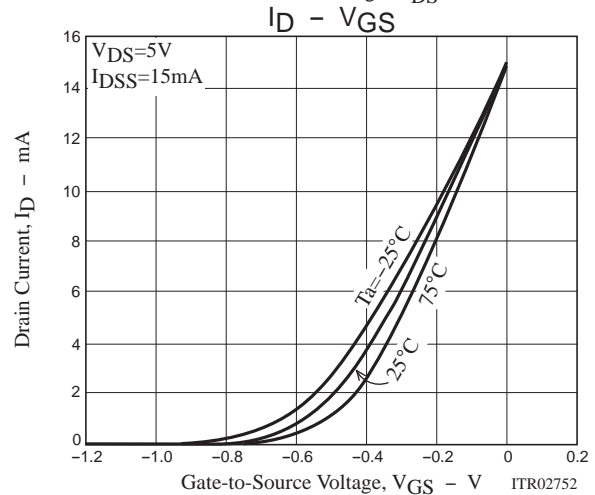
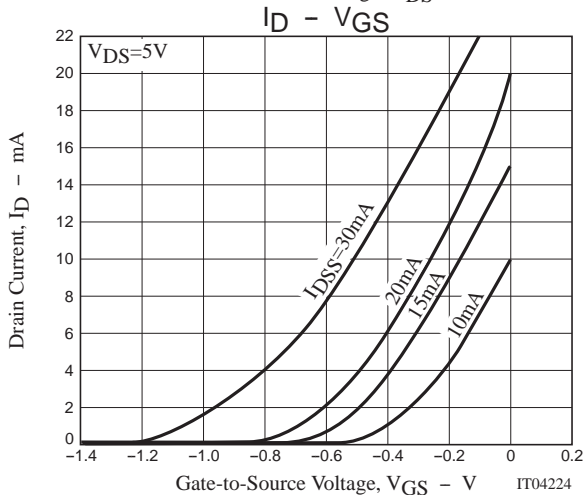
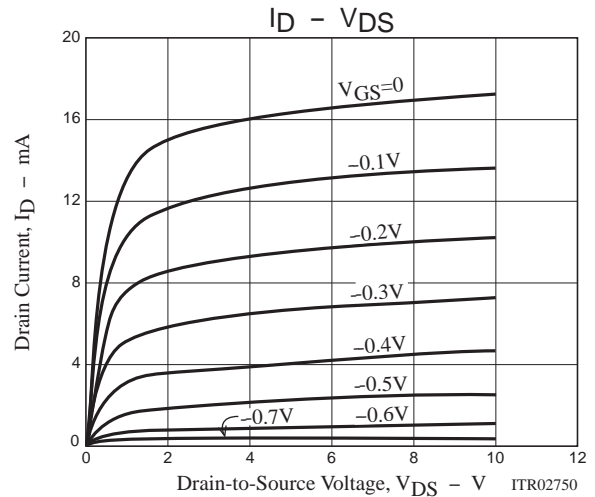
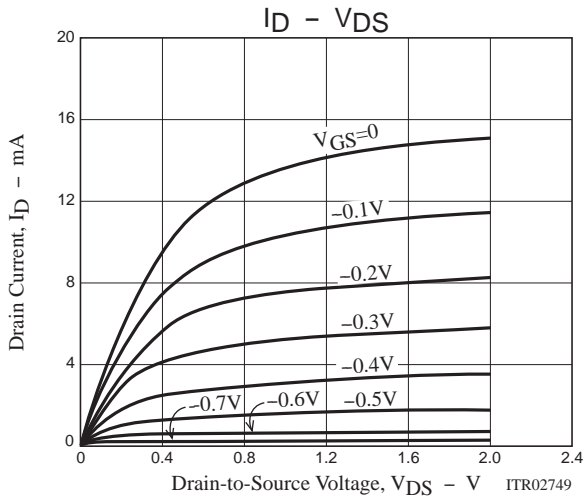
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	V(BR)GDS	I <sub>G</sub> =-10μA, V <sub>DS</sub> =0V	-15			V
Gate Cutoff Current	I <sub>GSS</sub>	V <sub>GS</sub> =-10V, V <sub>DS</sub> =0V			-1.0	nA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =100μA	-0.3	-0.7	-1.5	V
Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =5V, V <sub>GS</sub> =0V	10*		32*	mA
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> =5V, V <sub>GS</sub> =0V, f=1kHz	24	35		mS
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =5V, V <sub>GS</sub> =0V, f=1MHz		10.0		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	V <sub>DS</sub> =5V, V <sub>GS</sub> =0V, f=1MHz		2.9		pF
Noise Figure	NF	V <sub>DS</sub> =5V, R <sub>G</sub> =1kΩ, I <sub>D</sub> =1mA, f=1kHz		1.0		dB

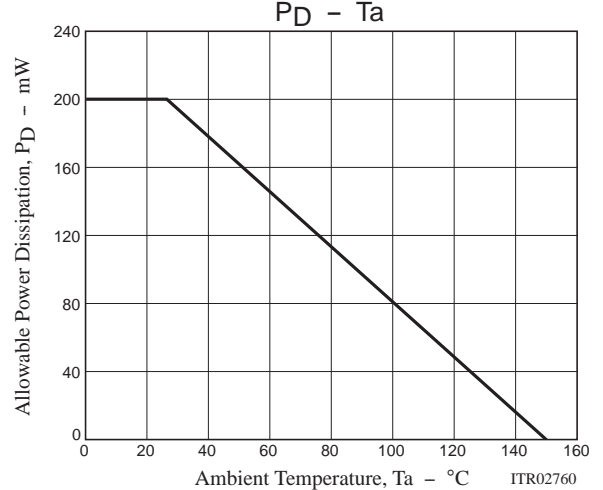
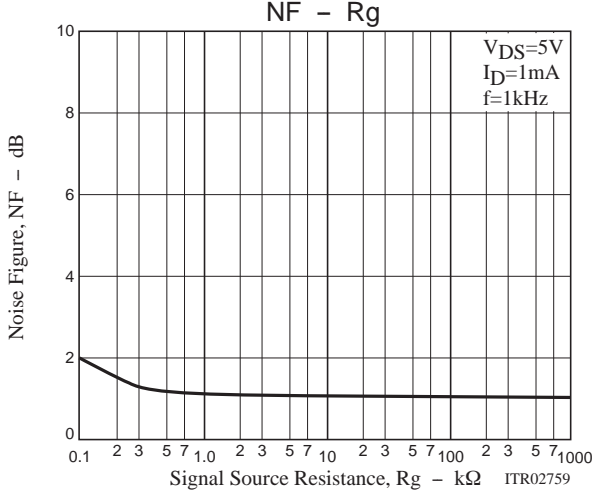
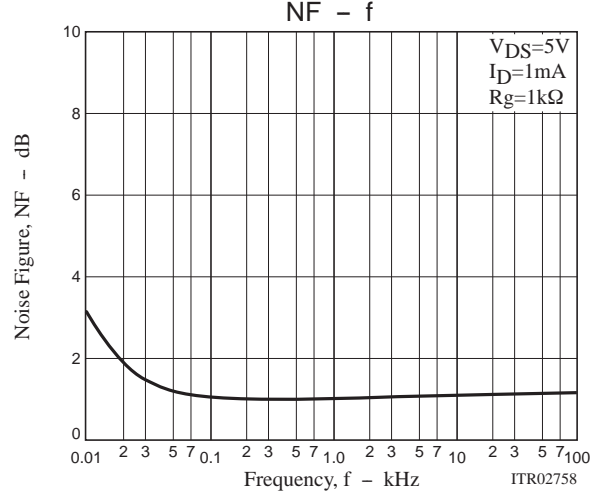
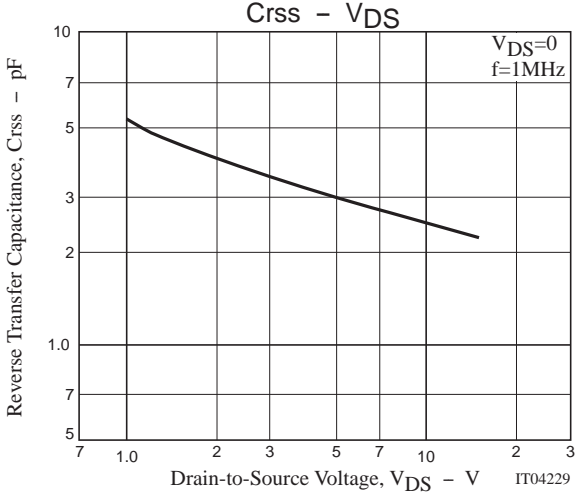
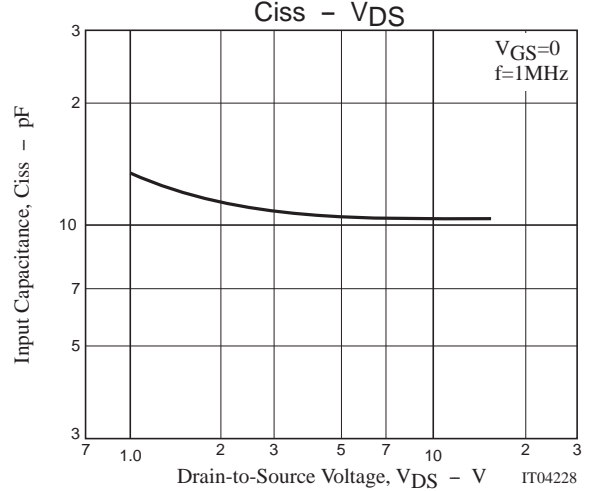
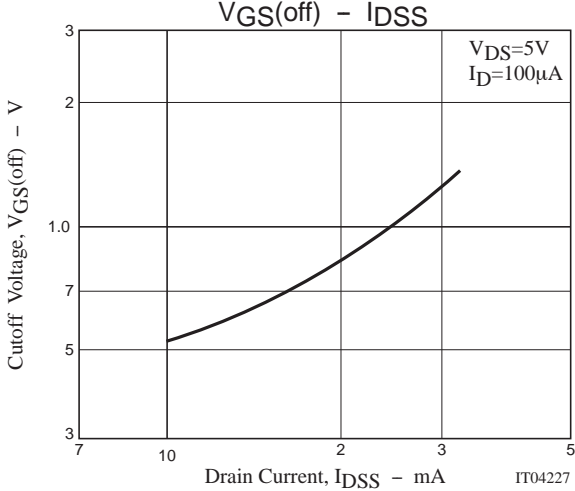
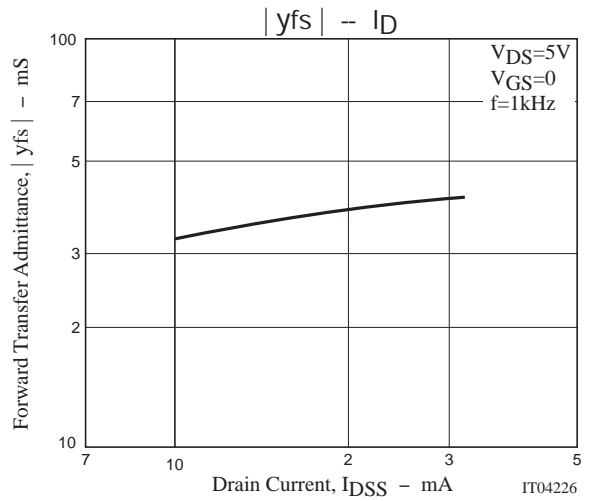
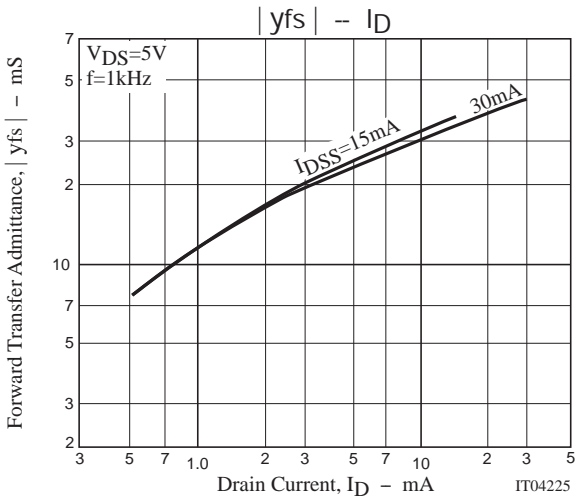
\* : The 2SK3557 is classified by I<sub>DSS</sub> as follows : (unit : mA)

Rank	6	7
I <sub>DSS</sub>	10.0 to 20.0	16.0 to 32.0

## Ordering Information

Device	Package	Shipping	memo
2SK3557-6-TB-E	CP	3,000pcs./reel	Pb Free
2SK3557-7-TB-E	CP	3,000pcs./reel	





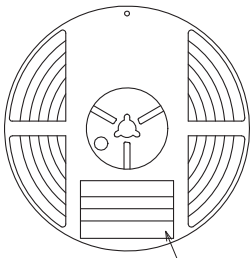
Embossed Taping Specification

2SK3557-6-TB-E, 2SK3557-7-TB-E

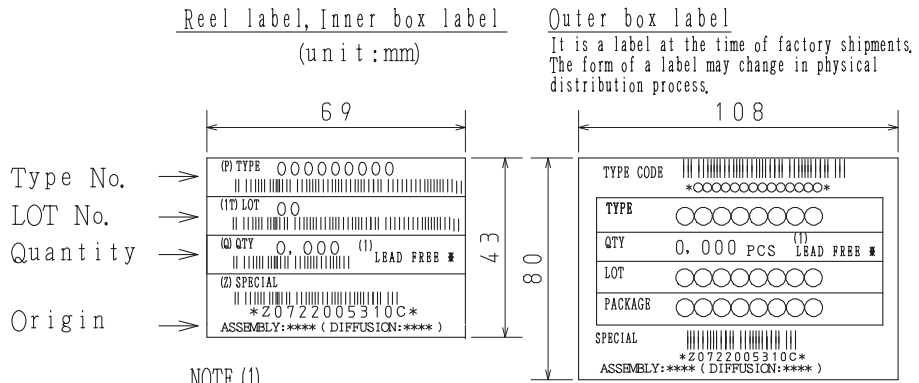
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CP	CP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

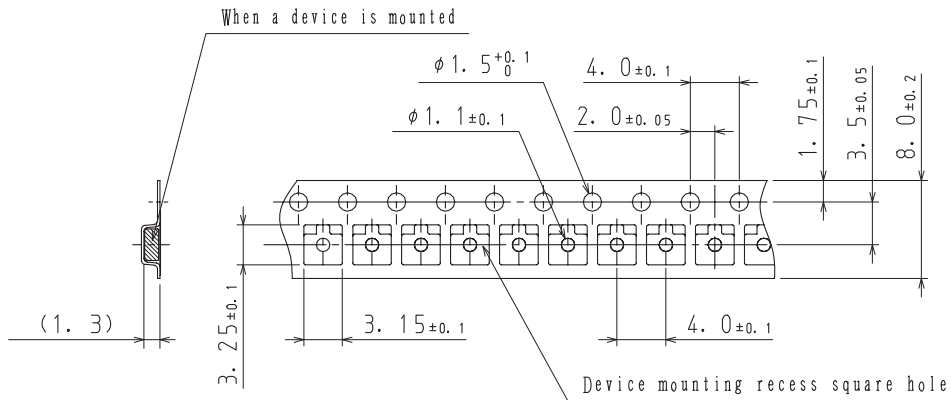


Reel label

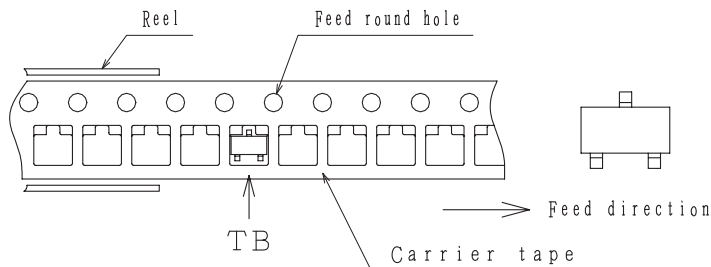


2. Taping configuration

2-1. Carrier tape size (unit:mm)



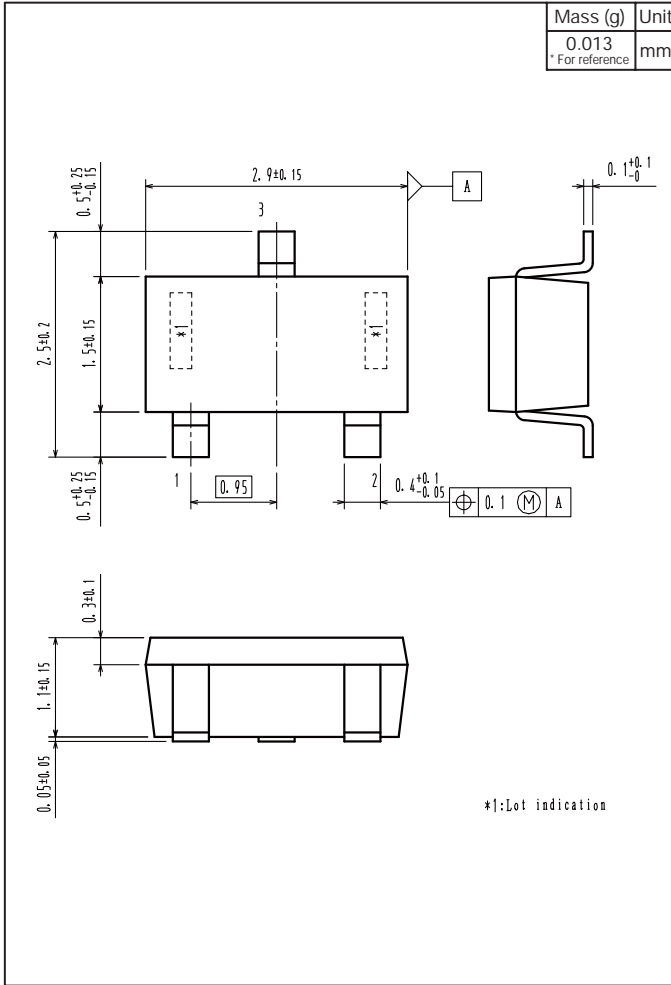
2-2. Device placement direction



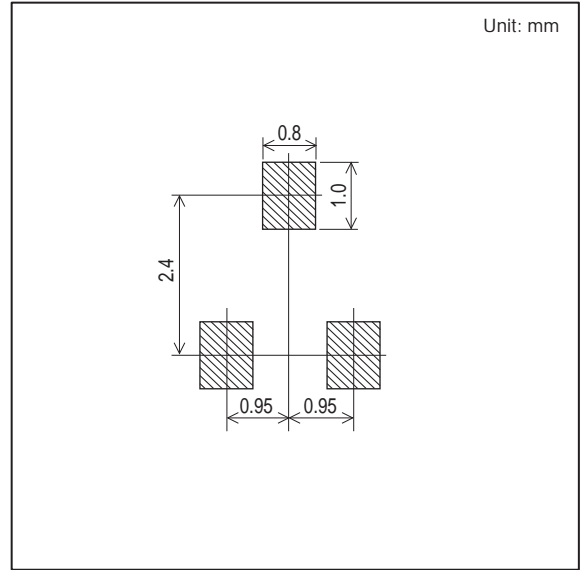
Those with one electrode terminal on the feed hole side.....TB

Outline Drawing

2SK3557-6-TB-E, 2SK3557-7-TB-E



Land Pattern Example



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